



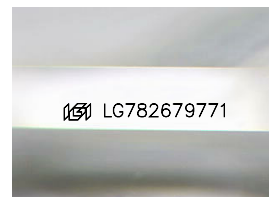
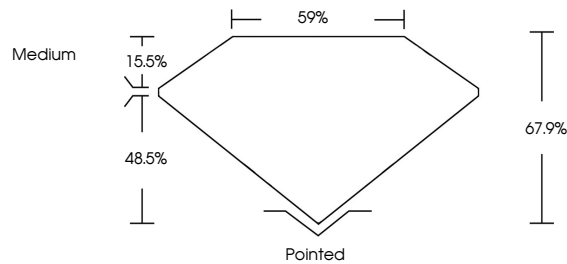
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LABORATORY GROWN DIAMOND REPORT

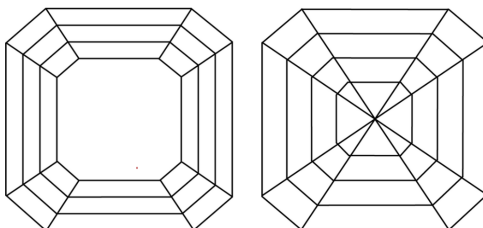
LG782679771
Report verification at [igi.org](https://www.igi.org)

PROPORTIONS



Sample Image Used

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

COLOR

D E F G H I J Faint Very Light Light

CLARITY

FL	IF	VVS ¹⁻²	VS ¹⁻²	SI ¹⁻²	I ¹⁻³
Flawless	Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included



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LABORATORY GROWN DIAMOND REPORT



March 12, 2026

IGI Report Number **LG782679771**

Description	LABORATORY GROWN DIAMOND
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Shape and Cutting Style **SQUARE EMERALD CUT**

Measurements **4.36 X 4.30 X 2.92 MM**

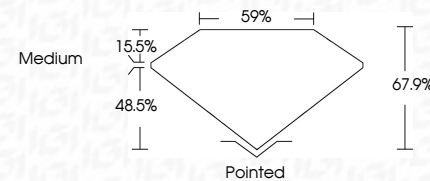
GRADING RESULTS

Carat Weight **0.51 CARAT**

Color Grade	E
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Clarity Grade **VVS 2**

Cut Grade **EXCELLENT**



ADDITIONAL GRADING INFORMATION

Polish **EXCELLENT**Symmetry **EXCELLENT**Fluorescence **NONE**

Inscription(s) LG782679771

Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process.
Type IIa



IG

March 12, 2026	
IGI Report No. IGR762679711	
SQUARE EMERALD CUT	
4.35 X 4.30 X 2.92 MM	
Carat Weight	0.51 CARAT
Color Grade	E
Clarity Grade	VVS 2
Cut Grade	EXCELLENT
Depth	67.1%
Table	59%
Girdle	Medium
Culet	Pointed
Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscriptions(s)	IGI IGR762679711
Comments:	
	The Laboratory Grown Diamond was found to be a Natural Vapor Deposition (VD) growth process. Type Ila

Comments:
This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process.